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Structure : Silicon Monolithic Integrated Circuit
Product Name : Power Driver For Compact Disc Players

Device Name : BA5826FP

Features : • 4-ch BTL driver

Use of an HSOP28 power package can achieve downsizing of the set.

• Gain can be controlled by attaching an external resistance.

• A built-in thermal shutdown circuit installed.

• A built-in 3.3V regulator installed. (External PNP Tr must be installed.)

• A built-in general operational amplifier installed.

• A built-in 2.7V reset circuit installed.

• Using an external capacitor, the reset delay time can be changed.

O ABSOLUTE MAXIMUM RATINGS (Ta=25°C)]

| Parameter | Symbol | Limits | Unit |
|--------------------------------|--------|------------|------|
| Power Supply Voltage | VCC | 13.5 | V |
| Power Dissipation | Pd | 1.7 *1 | W |
| Operating Temperature Range | Topr | -35 to 85 | °C |
| Storage Temperature Range | Tstg | -55 to 150 | °C |

^{*1} When mounted on the glass/epoxy board with the size: 70 mm×70 mm, the thickness: 1.6 mm, and the rate of copper foil occupancy area: 3% or less.

Over Ta=25°C, derating at the rate of 13.6mW/°C.

O OPERATING CONDITIONS

| Parameter | Symbol | Limits | Unit |
|----------------------|--------|----------|------|
| Power Supply Voltage | VCC | 4.5 to 9 | V |

This product has not been checked for the strategic materials (or service) defined in the Foreign Exchange and Foreign Trade Control Low of Japan so that a verification work is required before exporting it.

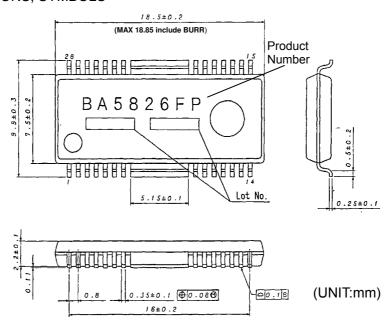
Not designed for radiation resistance.



O ELECTRIC CHARACTERISTICS (Ta=25°C, Vcc=8V, VBIAS=1.65V, R_L=8Ω, unless otherwise noted.)

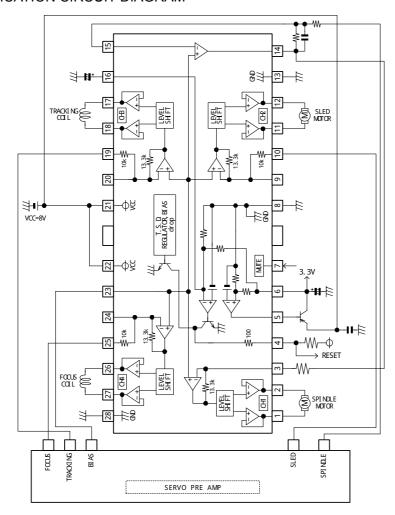
| Parameter | Symbol | MIN. | TYP. | MAX | Unit | Condition |
|--|---------------------------|------|------|------|----------|------------------------------------|
| Circuit Current at no signal | ICC | 6.0 | 10.0 | 14.0 | MA | No load applied |
| <ch1></ch1> | | | | | | |
| Output Offset Voltage | V001 | -50 | - | 50 | MV | |
| Maximum Output Amplitude | VOM1 | 4.35 | 5.0 | - | V | VBIAS=4V |
| Closed Circuit Voltage Gain | GVC1 | 6.0 | 8.0 | 10.0 | DB | |
| <ch2, 3,="" 4=""></ch2,> | | | | | | |
| Output Offset Voltage | VOO2 | -50 | - | 50 | mV | |
| Maximum Output Amplitude | VOM2 | 4.3 | 4.9 | - | V | VBIAS=4V |
| Closed Circuit Voltage Gain | GVC2 | 7.0 | 8.0 | 9.0 | dB | |
| <mute></mute> | | | | | | |
| Mute OFF Voltage | VMTOFF | 2.0 | - | - | V | |
| Mute ON Voltage | VMTON | 1 | - | 0.5 | V | |
| Bias Drop Mute Threshold | VBTHR | - | 0.7 | 1.2 | V | |
| Voltage | VDITIIX | _ | 0.7 | 1.2 | V | |
| <3.3V Regulator > | | | | | | |
| Output Voltage | Vreg | 3.13 | 3.3 | 3.47 | V | IL=100mA |
| Output Load Regulation | ∆VRL | -20 | 0 | 10 | mV | IL=100 to 200mA |
| Power Supply Voltage | ΔVVCC | -10 | 0 | 35 | mV | (Vcc=6 to 9V) IL=100mA |
| Regulation | AVVCC | -10 | U | 33 | IIIV | (VCC-0 to 9V) IE- 100IIIA |
| <operational amplifier=""></operational> | | | | | | |
| Offset Voltage | VOFOP | -6 | - | 6 | mV | |
| Input Bias Current | IBIAS | - | - | 300 | nA | |
| High-level Output Voltage | VOHOP | 7.5 | - | - | V | VBIAS=4V |
| Low-level Output Voltage | VOLOP | - | - | 0.3 | V | VBIAS=4V |
| Output Driving Current | ISOU | 300 | 500 | _ | μA | VBIAS=4V |
| Source | | | | | • | |
| Output Driving Current Sink | ISIN | 1 | - | - | mA | VBIAS=4V |
| | <reset output=""></reset> | | | | | |
| Reset ON Threshold Voltage | VTHR | 2.56 | 2.7 | 2.84 | V | When Vreg drops |
| Reset ON Output Voltage | VRON | _ | _ | 0.5 | V | Connected to 3.3V with the |
| | | | | 0.0 | • | resistance of $10k\Omega$ applied. |
| <reset output="" τ=""></reset> | | | | | | |
| <reset current="" τ=""></reset> | IREST | 16.6 | 23.7 | 30.8 | μΑ | |
| Reset τ Threshold Voltage H | VRESTH | 7.7 | | - | V | VREST=1.5V |
| Reset τ Threshold Voltage L | VRESTL | - | - | 0.4 | V | VREST=1V |

O OUTLINE DIMENSIONS, SYMBOLS



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O APPLICATION CIRCUIT DIAGRAM



CH1: SPINDLE CH2: SLED CH3: TRACKING CH4: FOCUS

T. S. D.: Thermal shutdown

Resistance unit: $[\Omega]$

O PIN NUMBERS, PIN NAMES

| No. | Pin Name | Description | No. | Pin Name | Description |
|-----|----------|--|-----|----------|--------------------------------------|
| 1 | VO1(-) | Driver CH1 negative output | | OPIN | Operational amplifier inverted input |
| 2 | VO1(+) | Driver CH1 positive output | 16 | RESETτ | Reset τ terminal |
| 3 | IN1 | CH1 input terminal | 17 | VO3(-) | Driver CH3 negative output |
| 4 | RESET | Reset output | 18 | VO3(+) | Driver CH3 positive output |
| 5 | REGB | Regulator external Tr base connection terminal | 19 | IN3 | CH3 input terminal |
| 6 | REGOUT | Regulator output | 20 | IN3' | CH3 input terminal for gain control |
| 7 | MUTE | Driver mute control terminal | 21 | VCC | Power supply input |
| 8 | GND | PREGND, REGGND | 22 | VCC | Power supply input |
| 9 | IN2' | CH2 input terminal for gain control | 23 | BIAS | Bias input |
| 10 | IN2 | CH2 input terminal | 24 | IN4' | CH4 input terminal for gain control |
| 11 | VO2(+) | Driver CH2 positive output | 25 | IN4 | CH4 input terminal |
| 12 | VO2(-) | Driver CH2 negative output | 26 | VO4(+) | Driver CH4 positive output |
| 13 | GND | CH2,3 POWGND | 27 | VO4(-) | Driver CH4 negative output |
| 14 | OPOUT | Operational amplifier output | 28 | GND | CH1,4 POWGND |

Note: The positive or negative polarity of driver outputs is determined by the input polarity. When the signal H is applied to the input pin, the negative output pin outputs L and the positive output pin outputs H.



CAUTIONS ON USE

(1) Relationship between the mute function and the reset output

| tolationionip botteon the mate ranotton and the recot output | | | | |
|--|--------------------------|--------------|--|--|
| Function | Driver Mute Operation | Reset output | | |
| Regulator voltage drop | | 'H'→'L' | | |
| Bias voltage drop | ON in all cases | 'H'→'L' | | |
| Thermal shutdown | | 'H'→'L' | | |
| Mute (pin 7) | | Constant | | |

[Regulator Voltage Drop]

When the regulator voltage drops to 2.7V (typ.) or less, the reset output will become 'L' while the mute function will turn ON and, when the voltage recovers to 2.9V (typ.) or above, the reset output will become 'H' while the mute function will turn OFF.

[Bias Drop]

When the bias terminal (pin 23) voltage has dropped to 0.7V (typ.) or less, the mute function will turn ON while the reset output will become 'L'. Under conditions of normal use, it should be set to 1.2V or above.

[Thermal Shutdown]

When the chip temperature has reached to 175°C (typ.) or above, the mute function will turn ON while the reset output will become 'L'. Ten the chip temperature has dropped to 150°C (typ.) or less, the mute function will turn OFF while the reset output will become 'H'. [Mute]

When the mute terminal (pin 7) voltage has set to open or dropped to 0.5V (typ.) or less, the mute function will turn ON while the reset output will not change.

(2) About reset τ terminal

Inserting a capacitor between the reset τ terminal (pin 16) and GND can set the delay time for the reset output.

The delay time t [sec] can be expressed by the following equation, where C[F] is a capacitance of the capacitor to be connected;

t=CV/I

When V=1.14[V], I=23.7[μ A] (typ.) and the capacitor with the capacitance of 4.7 μ F is connected, the delay time will become approximately 220msec.

- (3) Thermal shutdown (TSD), mute ON, bias terminal voltage drop, or regulator voltage drop will activate the mute function, where only the driver part can be muted. While muting, the voltage at the output terminal will equal to the internal bias voltage (approximately (VCC-VF) / 2).
- (4) The capacitor installed between the regulator output (pin 6) and GND also serves as an anti-oscillation capacitor and therefore, it is required to have high performance in the temperature characteristics.
- (5) While the regulator is not in use, the regulator output terminal (pin 6) must be shorted to VCC and the regulator external Tr base connection terminal (pin 5) must be open.
- (6) The radiating FIN must be connected to the external GND.
- (7) Short-circuits between output pin-VCC, output pin-GND, or output terminals (load short) must be avoided. Make sure that the ICs are installed on the board in proper directions. Mounting the ICs in improper directions may damage them or produce smoke.
- (8) About absolute maximum ratings

Exceeding the absolute maximum ratings, such as the applied voltage or the operating temperature range, may cause permanent device damage. As these cases cannot be limited to the broken short mode or the open mode, if a special mode where the absolute maximum ratings may be exceeded is assumed, it is recommended to take mechanical safety measures such as attaching fuses.

(9) About power supply lines

As a measure against the back current regenerated by a counter electromotive force of the motor, a capacitor to be used as a regenerated-current path can be installed between the power supply and GND and its capacitance value should be determined after careful check that any problems, for example, a leak capacitance of the electrolytic capacitor at low temperature, are not found in various characteristics.

(10) About GND potential

The electric potential of the GND terminal must be kept lowest in the circuitry at any operation states.

(11) About thermal design

With consideration of the power dissipation (Pd) under conditions of actual use, a thermal design



provided with an enough margin should be done.

(12) About operations in a strong electric field

When used in a strong electric field, note that a malfunction may occur.

(13) ASO

When using this IC, the output Tr. must be set not to exceed the values specified in the absolute maximum ratings and ASO.

(14) Thermal shutdown circuit

This IC incorporates a thermal shutdown circuit (TSD circuit). When the chip temperature reaches the value shown below, the coil output to the motor will be set to open.

The thermal shutdown circuit is designed only to shut off the IC from a thermal runaway and not intended to protect or guarantee the entire IC functions.

Therefore, users cannot assume that the TSD circuit once activated can be used continuously in the subsequent operations.

| TSD ON Temperature | Hysteresis Temperature |
|--------------------|------------------------|
| [°C] (typ.) | [°C] (typ.) |
| 175 | 25 |

(15) About earth wiring patterns

When a small signal GND and a large current GND are provided, it is recommended that the large current GND pattern and the small signal GND pattern should be separated and grounded at a single point of the reference point of the set in order to prevent the voltage of the small signal GND from being affected by a voltage change caused by the resistance of the pattern wiring and the large current. Make sure that the GND wiring patterns of the external components will not change, too.

(16) This IC is a monolithic IC which has a P⁺ isolations and P substrate to isolate elements each other. This P layer and an N layer in each element form a PN junction to construct various parasitic elements. Due to the IC structure, the parasitic elements are inevitably created by the potential relationship. Activation of the parasitic elements can cause interference between circuits and may result in a malfunction or, consequently, a fatal damage. Therefore, make sure that the IC must not be used under conditions that may activate the parasitic elements, for example, applying the lower voltage than the ground level (GND, P substrate) to the input terminals.

Note that, while not applying the power supply voltage to the IC, any voltage must not be applied to the input terminals. In addition, do not applying the voltage to input terminals without applying the power supply voltage to the IC. Also while applying the power supply voltage, each input terminal must be the power supply voltage or less; or within the guaranteed values in the electric characteristics.

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